

isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 100V(Min)
- · High Current Capability
- · Wide Area of Safe Operation
- · Complement to Type 2SB1230
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

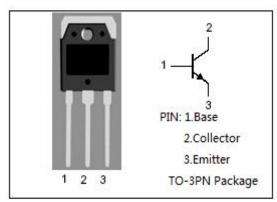
APPLICATIONS

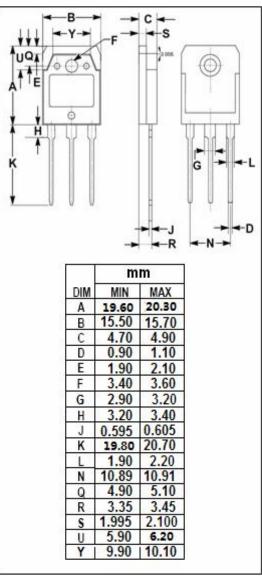


• Designed for motor drivers, converters and other general high-current switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	110	V	
V _{CEO}	Collector-Emitter Voltage	100	V	
V _{EBO}	Emitter-Base Voltage	6	V	
Ic	Collector Current-Continuous 15		Α	
Icp	Collector Current-Pulse 25		А	
l _Β	Base Current-Continuous	5	А	
	Collector Power Dissipation @ T _a =25°C	3	W	
Pc	Collector Power Dissipation @ T_c =25 $^{\circ}$ C	100		
TJ	Junction Temperature	150 ℃		
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$	







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2SD1840

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I_C = 5mA; R_{BE} = ∞	100			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	110			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	6			V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 0.6A			0.8	V
$V_{\text{BE}(\text{sat})}$	Base -Emitter Saturation Voltage	I _C = 6A; I _B = 0.6A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			100	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μА
h _{FE-1}	DC Current Gain	I _C = 1.5A; V _{CE} = 2V	50		140	
h _{FE-2}	DC Current Gain	I _C = 6A; V _{CE} = 2V	20			

♦ h_{FE-1} Classifications

Р	Q		
50-100	70-140		

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